

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Collector Current	Ic	4	А
Peak Collector Current	I _{CM}	8	А
Base Current	IB	2	А
Peak Base Current	I _{BM}	4	А

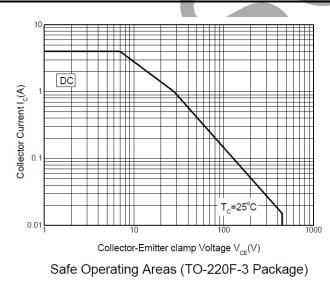
Thermal (Characteristics	(@T _A = +25°C,	unless otherwise specified.)
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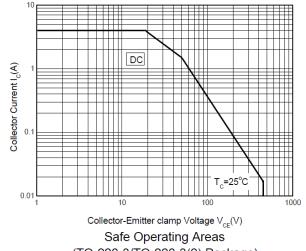
Characteristic		Symbol	Value	Unit	
Dower Dissinction @T = 125°C	For TO220F-3		28	W	
Power Dissipation $@T_C = +25^{\circ}C$	For TO220AB Type C	- PD	75	VV	
Thermal Desistance, lunction to Coos	For TO220F-3		4.5	°C/W	
Thermal Resistance, Junction to Case	For TO220AB Type C	- R _{ejc}	1.67	C/VV	
Operating and Storage Temperature Range		T _J ,T _{STG}	-65 to +150	°C	

ESD Ratings (Note 6)				
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Note:

Safe Operating Areas (@T_A = +25°C, unless otherwise specified.)







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

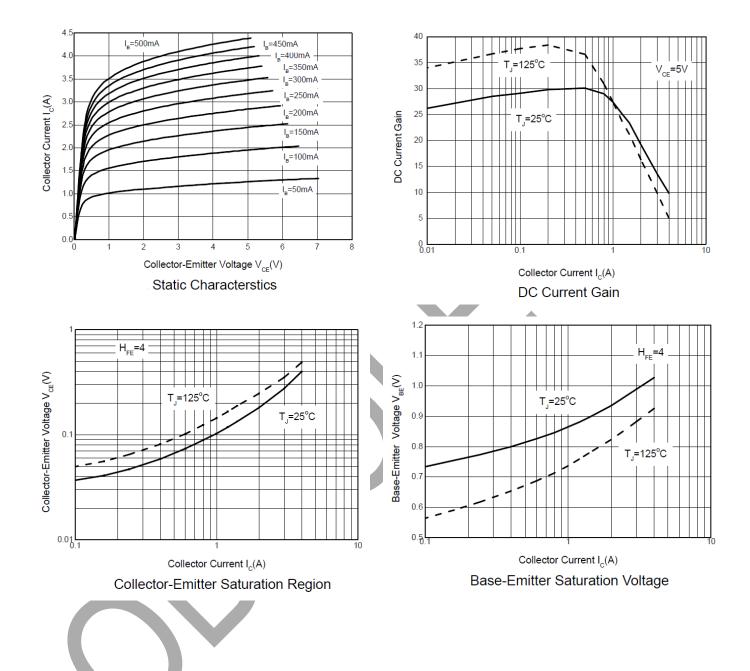
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	—		V	I _C = 100μΑ, V _{BE} = 0V
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	—	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	_	V	I _E = 100μA
Collector Cutoff Current	ICEV	_	—	10	μA	V _{CE} = 700V, V _{BE} = -1.5V
DC current transfer Static ratio (Note 5)	h _{FE}	15 8	_	35 35	_	I _C = 1A, V _{CE} = 5V I _C = 2A, V _{CE} = 5V
Collector-Emitter Saturation Voltage (Note 5)	V _{CE(sat)}		 	0.3 0.6 0.9	V	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$ $I_{C} = 4A, I_{B} = 1A$
Base-Emitter Saturation Voltage (Note 5)	V _{BE(sat)}	_		1.1 1.3	v	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$
Output Capacitance	Cob	_	45	—	pF	V _{CB} = 10V, f = 0.1MHz
Transition Frequency	fT	4	_	-	MHz	I _C = 0.5A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	_	_	0.8		
Storage Time with Resistive Load	ts	_	—	4.5	μs	$I_{\rm C} = 2A, V_{\rm CC} = 125V$
Fall Time with Resistive Load	t _f		—	0.9		$I_{B1} = -I_{B2} = 0.4A$

Note:

te: 5. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

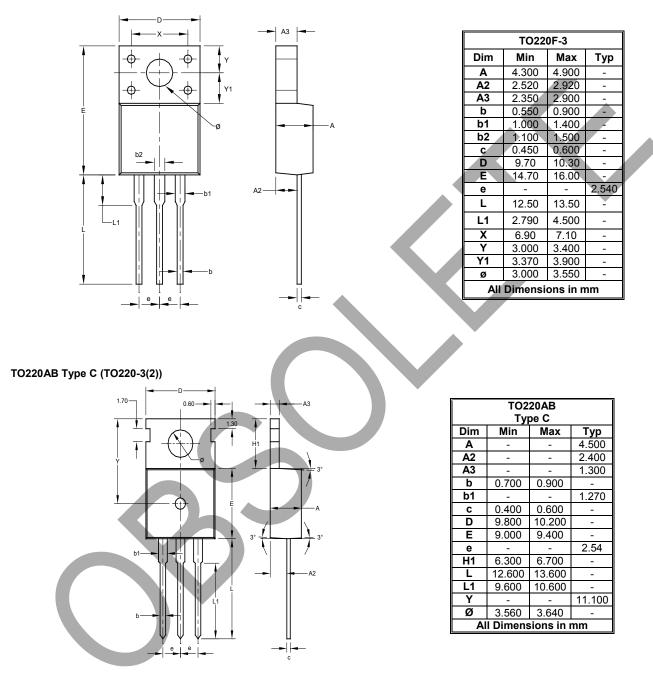




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

TO220F-3



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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